



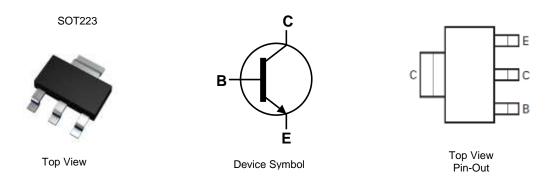
### 25V NPN HIGH CURRENT TRANSISTOR IN SOT223

### **Features**

- BV<sub>CEO</sub> > 25V
- I<sub>C</sub> = 7A High Continuous Collector Current
- I<sub>CM</sub> = 20A Peak Pulse Current
- Very Low Saturation Voltage V<sub>CE(SAT)</sub> < 110mV @ 1A</li>
- R<sub>CE(SAT)</sub> = 36mΩ at 5A for a Low Equivalent On-Resistance
- hFE Specified Up to 20A for a High Gain Hold Up
- P<sub>TOT</sub> = 3W
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

## **Mechanical Data**

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound.
   UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads.
   Solderable per MIL-STD-202, Method 208<sup>3</sup>
- Weight: 0.112 grams (Approximate)



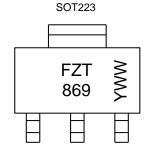
## Ordering Information (Note 4)

| Product  | Compliance | Marking | Reel Size (inches) | Tape Width (mm) | Quantity per Reel |
|----------|------------|---------|--------------------|-----------------|-------------------|
| FZT869TA | AEC-Q101   | FZT869  | 7                  | 12              | 1,000             |

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



FZT 869 = Product Type Marking Code YWW = Date Code Marking Y or  $\overline{Y}$  = Last Digit of Year (ex: 7 = 2017) WW or  $\overline{W}W$  = Week Code (01–53)



# Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characteristic               | Symbol           | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage       | V <sub>CBO</sub> | 60    | V    |
| Collector-Emitter Voltage    | V <sub>CEO</sub> | 25    | V    |
| Emitter-Base Voltage         | V <sub>EBO</sub> | 6     | V    |
| Continuous Collector Current | I <sub>C</sub>   | 7     | Α    |
| Peak Pulse Current           | I <sub>CM</sub>  | 20    | А    |

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                               | Symbol                           | Value            | Unit        |            |
|----------------------------------------------|----------------------------------|------------------|-------------|------------|
| Power Dissipation                            | (Note 5)                         |                  | 3<br>24     | W<br>mW/°C |
| Linear Derating Factor                       | (Note 6)                         | P <sub>D</sub>   | 1.6<br>12.8 |            |
| Thermal Desistance Junction to Ambient       | (Note 5)                         | R <sub>0JA</sub> | 42          |            |
| Thermal Resistance, Junction to Ambient      | (Note 6)                         | R <sub>0JA</sub> | 78          | °C/W       |
| Thermal Resistance Junction to Lead (Note 7) |                                  | $R_{\theta JL}$  | 8.8         |            |
| Operating and Storage Temperature Range      | T <sub>J,</sub> T <sub>STG</sub> | -55 to +150      | °C          |            |

### ESD Ratings (Note 8)

| Characteristic                             | Symbol  | Value | Unit | JEDEC Class |
|--------------------------------------------|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V    | 3A          |
| Electrostatic Discharge - Machine Model    | ESD MM  | 400   | V    | С           |

Notes:

- 5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.

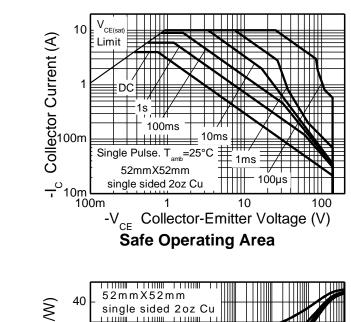
  6. Same as note (5), except the device is mounted on 25mm x 25mm 1oz copper.

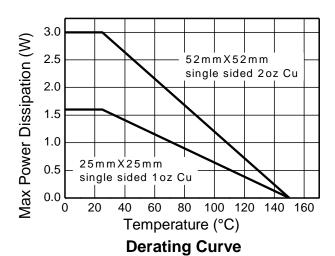
  7. Thermal resistance from junction to solder-point (at the end of the collector lead).

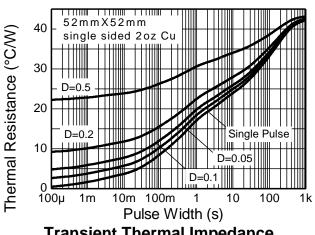
  8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

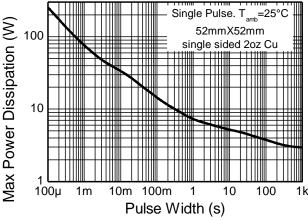


# **Thermal Characteristics and Derating Information**









**Transient Thermal Impedance** 

**Pulse Power Dissipation** 



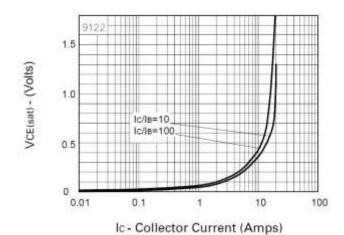
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                                 | Symbol               | Min | Тур | Max     | Unit     | Test Condition                                                          |
|------------------------------------------------|----------------------|-----|-----|---------|----------|-------------------------------------------------------------------------|
| Collector-Base Breakdown Voltage               | $BV_{CBO}$           | 60  | 120 | _       | V        | $I_{C} = 100 \mu A$                                                     |
| Collector-Emitter Breakdown Voltage            | BV <sub>CER</sub>    | 60  | 120 | _       | V        | $I_C = 1\mu A, R_B \le 1k\Omega$                                        |
| Collector-Emitter Breakdown Voltage (Note 9)   | BV <sub>CEO</sub>    | 25  | 35  | _       | V        | $I_C = 10mA$                                                            |
| Emitter-Base Breakdown Voltage                 | $BV_{EBO}$           | 6   | 8   | _       | V        | $I_{E} = 100 \mu A$                                                     |
| Collector Cut-off Current                      | I <sub>CBO</sub>     | _   | _   | 50<br>1 | nΑ<br>μΑ | V <sub>CB</sub> = 50V<br>V <sub>CB</sub> = 50V, T <sub>A</sub> = +100°C |
| Collector Cut-off Current                      | I <sub>CER</sub>     | _   | _   | 50<br>1 | nΑ<br>μΑ | $V_{CE} = 50V, R_B \le 1k\Omega$<br>$V_{CE} = 50V, T_A = +100$ °C       |
| Emitter Cut-off Current                        | I <sub>EBO</sub>     | _   | _   | 10      | nA       | $V_{EB} = 6V$                                                           |
|                                                |                      | 300 | 450 | _       | _        | I <sub>C</sub> = 10mA, V <sub>CE</sub> = 1V                             |
| DC Current Coin (Note 0)                       | L                    | 300 | 450 | _       |          | $I_C = 1A$ , $V_{CE} = 1V$                                              |
| DC Current Gain (Note 9)                       | h <sub>FE</sub>      | 200 | 300 | _       |          | $I_C = 7A$ , $V_{CE} = 1V$                                              |
|                                                |                      | 40  | 100 | _       |          | $I_C = 20A, V_{CE} = 2V$                                                |
|                                                | V <sub>CE(SAT)</sub> | _   | 35  | 50      |          | $I_C = 0.5 \text{mA}, I_B = 10 \text{mA}$                               |
| Collector-Emitter Saturation Voltage (Note 9)  |                      | _   | 67  | 110     | mV       | $I_C = 1A, I_B = 10mA$                                                  |
| Collector-Entitler Saturation Voltage (Note 9) |                      | _   | 168 | 215     | IIIV     | $I_C = 2A, I_B = 10mA$                                                  |
|                                                |                      | _   | _   | 350     |          | $I_C = 6.5A$ , $I_B = 150mA$                                            |
| Base-Emitter Saturation Voltage (Note 9)       | $V_{BE(SAT)}$        | _   | _   | 1.2     | V        | $I_C = 6.5A$ , $I_B = 300mA$                                            |
| Base-Emitter Turn-On Voltage (Note 9)          | V <sub>BE(ON)</sub>  | _   | _   | 1.13    | mV       | $I_C = 6.5A, V_{CE} = 1V$                                               |
| Current Gain-Bandwidth Product (Note 9)        | f⊤                   | _   | 100 | _       | MHz      | $I_{C} = 100 \text{mA}, V_{CE} = 10 \text{V},$<br>f = 50 MHz            |
| Output Capacitance                             | $C_{OBO}$            | _   | 70  | _       | pF       | $V_{CB} = 10V$ , $f = 1MHz$                                             |
| Switching Times                                | t <sub>ON</sub>      | _   | 60  | _       | ns       | $I_C = 1A, V_{CC} = 10V,$                                               |
| Owitering Tillies                              | toff                 | _   | 680 | _       | 115      | $I_{B1} = -I_{B2} = 100 \text{mA}$                                      |

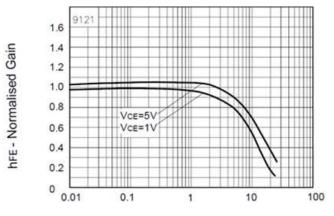
Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

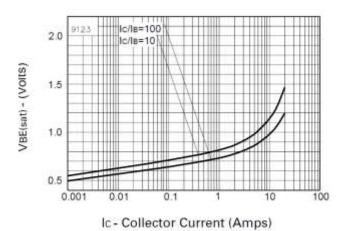


VCE(sat) v IC

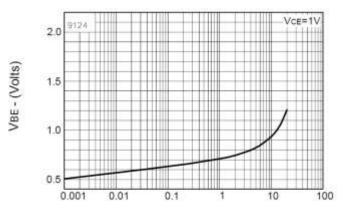


Ic - Collector Current (Amps)

### hFE v IC



VBE(sat) v IC



Ic - Collector Current (Amps)

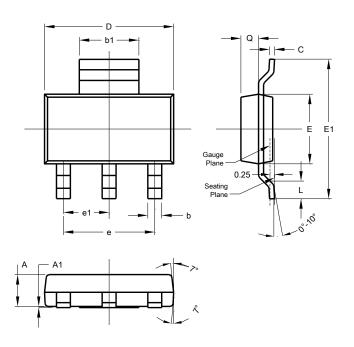
VBE(on) V IC



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### **SOT223**

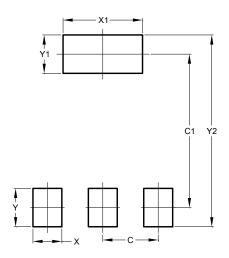


| SOT223               |       |      |      |  |  |
|----------------------|-------|------|------|--|--|
| Dim                  | Min   | Max  | Тур  |  |  |
| Α                    | 1.55  | 1.65 | 1.60 |  |  |
| A1                   | 0.010 | 0.15 | 0.05 |  |  |
| b                    | 0.60  | 0.80 | 0.70 |  |  |
| b1                   | 2.90  | 3.10 | 3.00 |  |  |
| С                    | 0.20  | 0.30 | 0.25 |  |  |
| D                    | 6.45  | 6.55 | 6.50 |  |  |
| Е                    | 3.45  | 3.55 | 3.50 |  |  |
| E1                   | 6.90  | 7.10 | 7.00 |  |  |
| е                    | -     | -    | 4.60 |  |  |
| e1                   | -     | -    | 2.30 |  |  |
| L                    | 0.85  | 1.05 | 0.95 |  |  |
| q                    | 0.84  | 0.94 | 0.89 |  |  |
| All Dimensions in mm |       |      |      |  |  |

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### **SOT223**



| Dimensions | Value (in mm) |  |  |
|------------|---------------|--|--|
| С          | 2.30          |  |  |
| C1         | 6.40          |  |  |
| Х          | 1.20          |  |  |
| X1         | 3.30          |  |  |
| Y          | 1.60          |  |  |
| Y1         | 1.60          |  |  |
| Y2         | 8 00          |  |  |

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.



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